

TOSHIBA Photocoupler GaAs IRed & Photo-Transistor

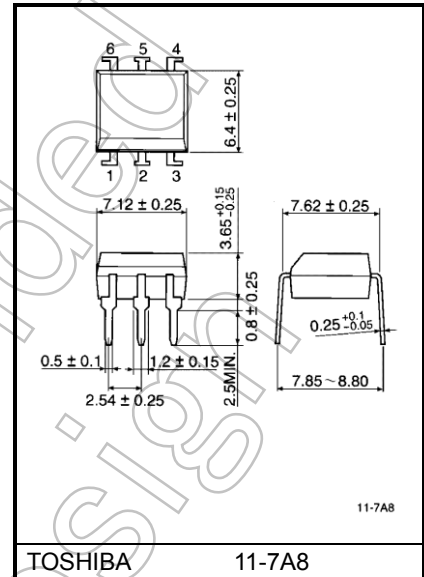
TLP631, TLP632

Programmable Controllers
AC/DC-Input Module
Solid State Relay

Unit: mm

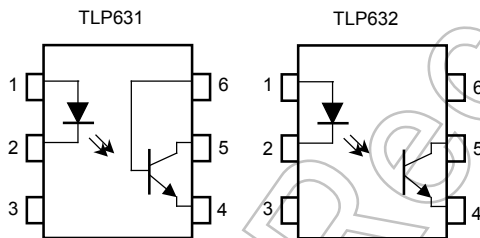
The TOSHIBA TLP631 and TLP632 consist of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.
TLP632 has no-base internal connection for high-EMI environments.

- Collector-emitter voltage: 55 V (min)
- Current transfer ratio: 50% (min)
Rank GB: 100% (min)
- Isolation voltage: 5000 Vrms (min)
- UL recognized: UL1577, file no. E67349
- cUL approved : CSA Component Acceptance Service
No. 5A, File No.E67349



Weight: 0.4 g (typ.)

Pin Configurations (top view)



1: Anode
2: Cathode
3: N.C.
4: Emitter
5: Collector
6: Base

1: Anode
2: Cathode
3: N.C.
4: Emitter
5: Collector
6: N.C

Start of commercial production
1983-05

Current Transfer Ratio

Classification (Note 1)	Current Transfer Ratio (%) (Ic/If)		Marking Of Classification
	If = 5 mA, VCE = 5 V, Ta = 25°C		
	Min	Max	
Blank	50	600	Blank, Y [■] , YE, G, G [■] , GR, B, BL, GB
Rank Y	50	150	YE, Y [■]
Rank GR	100	300	GR, G, G [■]
Rank BL	200	600	BL, B
Rank GB	100	600	GB, GR, G, G [■] , BL, B
Rank YH	75	150	Y [■]
Rank GRL	100	200	G
Rank GRH	150	300	G [■]
Rank BLL	200	400	B

Note 1: Ex, rank GB: TLP631 (GB)

Note: Application type name for certification test, please use standard product type name, i. e.

TLP631 (GB): TLP631

TLP632 (GB): TLP632

Not Recommended for New Design

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	60	mA
	Forward current derating (Ta ≥ 39°C)	$\Delta I_F/^\circ\text{C}$	-0.7	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Diode power dissipation	P_D	70	mW
	Diode power dissipation derating (Ta ≥ 39 °C)	$\Delta P_D/^\circ\text{C}$	-0.82	mW/°C
Detector	Collector-emitter voltage	V_{CEO}	55	V
	Collector-base voltage (TLP631)	V_{CBO}	80	V
	Emitter-collector voltage	V_{ECO}	7	V
	Emitter-base voltage (TLP631)	V_{EBO}	7	V
	Collector current	I_C	50	mA
	Power dissipation	P_C	150	mW
	Power dissipation derating (Ta ≥ 25°C)	$\Delta P_C/^\circ\text{C}$	-1.5	mW/°C
Storage temperature range		T_{stg}	-55 to 125	°C
Operating temperature range		T_{opr}	-55 to 100	°C
Lead soldering temperature (10s)		T_{sol}	260	°C
Total package power dissipation		P_T	250	mW
Total package power dissipation derating (Ta ≥ 25°C)		$\Delta P_T/^\circ\text{C}$	-2.5	mW/°C
Isolation voltage (AC, 60 s, R.H. ≤ 60%) (Note 1)		BV_S	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Device considered a two terminal device: LED side pins Shorted together and DETECTOR side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{CC}	—	5	24	V
Forward current	I_F	—	16	25	mA
Collector current	I_C	—	1	10	mA
Operating temperature	T_{opr}	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5V	—	—	10	μA
	Capacitance	C _T	V = 0 V, f = 1 MHz	—	30	—	pF
Detector	Collector-emitter breakdown voltage	V _{(BR) CEO}	I _C = 0.5 mA	55	—	—	V
	Emitter-collector breakdown voltage	V _{(BR) ECO}	I _E = 0.1 mA	7	—	—	V
	Collector-base breakdown voltage (TLP631)	V _{(BR) CBO}	I _C = 0.1 mA	80	—	—	V
	Emitter-base breakdown voltage (TLP631)	V _{(BR) EBO}	I _E = 0.1 mA	7	—	—	V
	Collector dark current	I _{CEO}	V _{CE} = 24 V	—	10	100	nA
			V _{CE} = 24 V, Ta = 85°C	—	2	50	μA
Capacitance collector to emitter	C _{CE}	V = 0 V, f = 1 MHz	—	10	—	pF	

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I _C /I _F	I _F = 5 mA, V _{CE} = 5 V Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	I _C /I _{F (sat)}	I _F = 1 mA, V _{CE} = 0.4 V Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 2.4 mA, I _F = 8 mA	—	—	0.4	V

Not Recommended for New

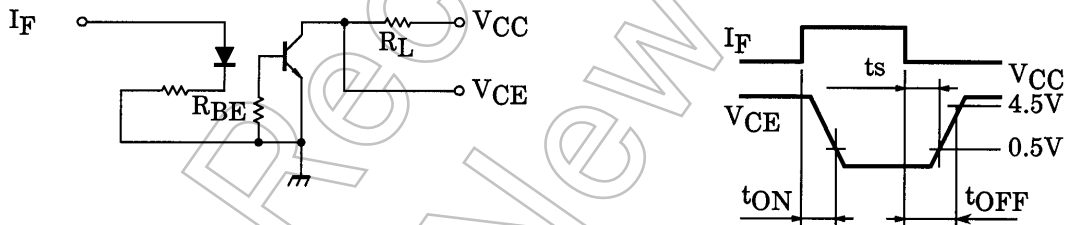
Isolation Characteristics (Ta = 25°C)

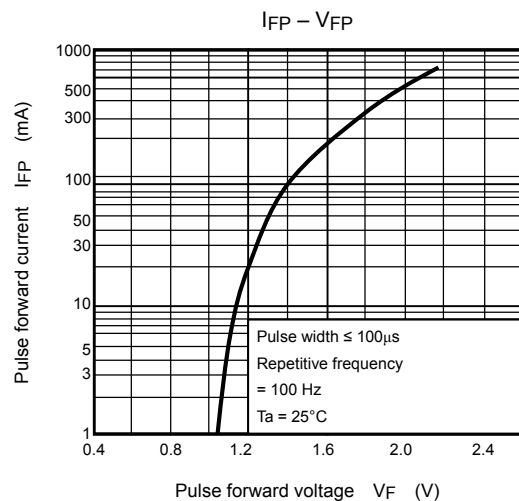
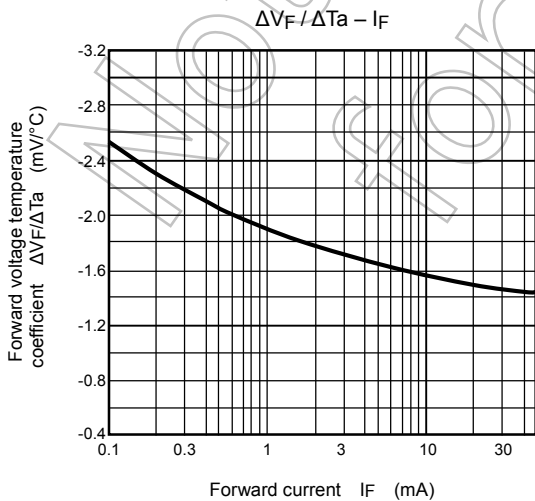
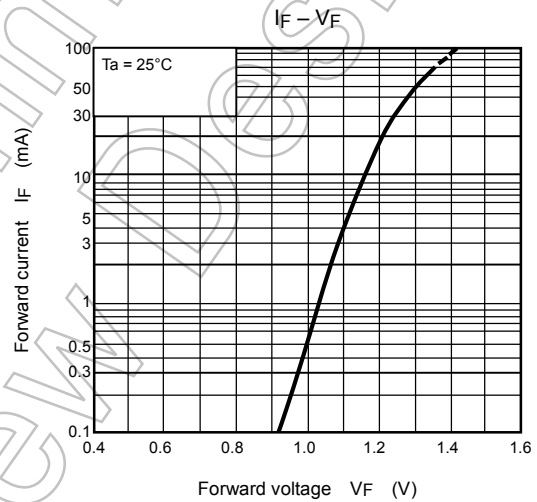
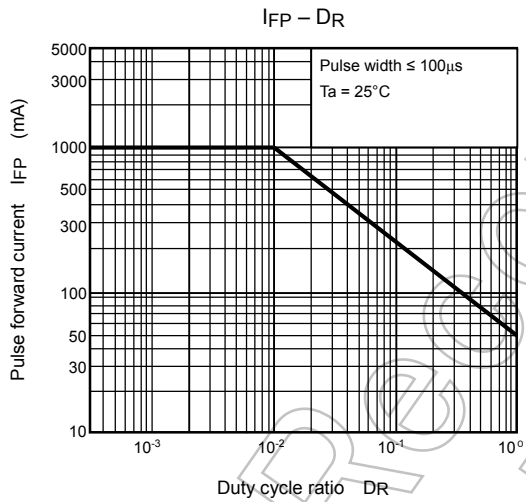
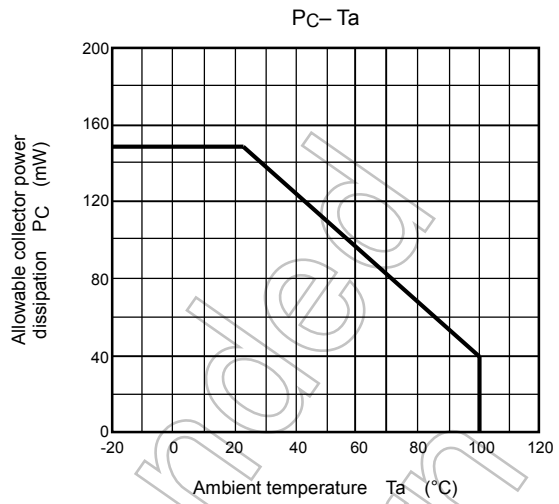
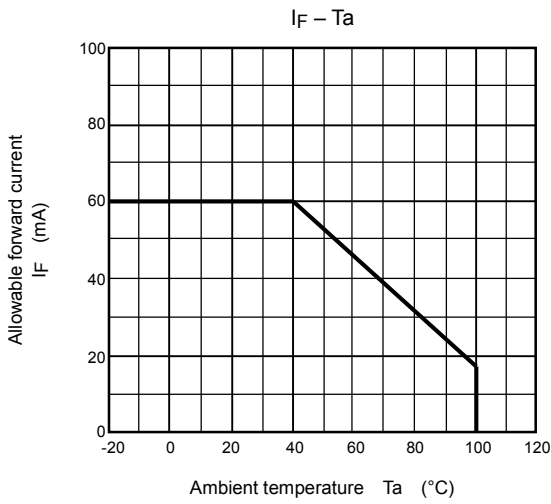
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance (input to output)	Cs	Vs = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	Rs	Vs = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	—	Ω
Isolation voltage	BVs	AC, 60 s	5000	—	—	Vrms
		AC, 1 s, in oil	—	10000	—	
		DC, 60 s, in oil	—	10000	—	Vdc

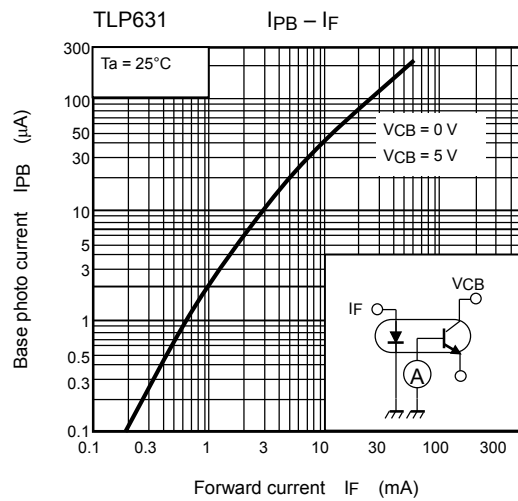
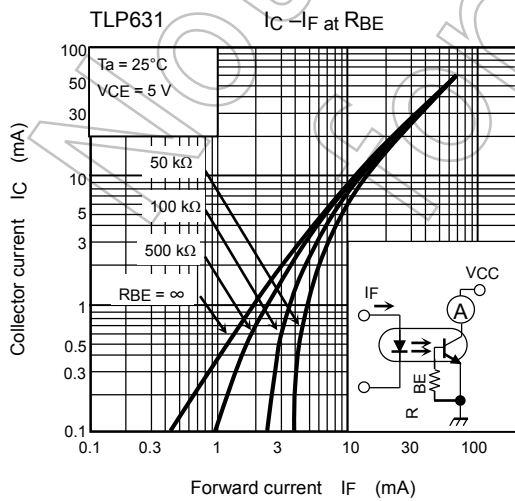
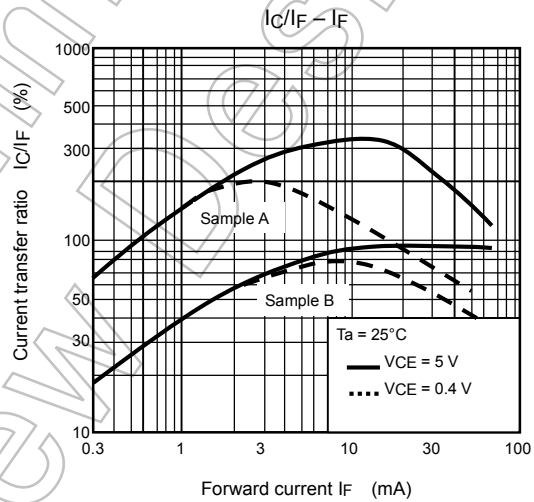
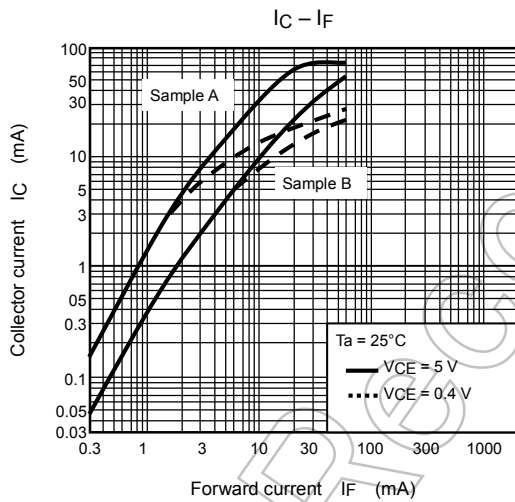
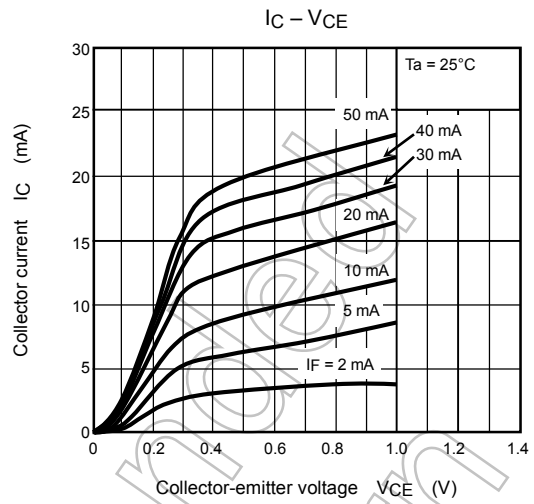
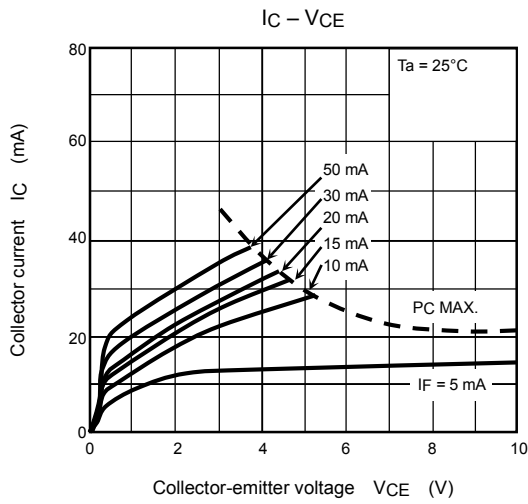
Switching Characteristics (Ta = 25°C)

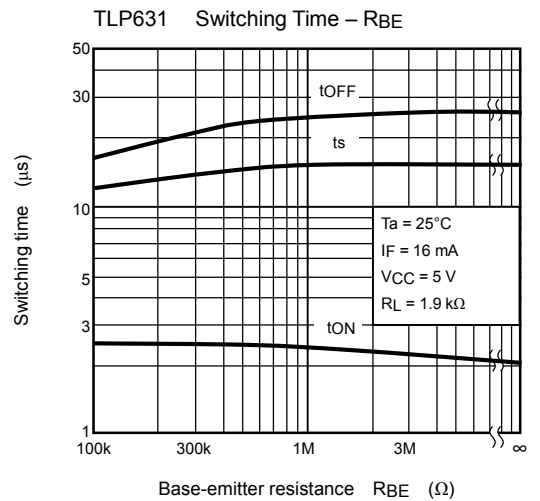
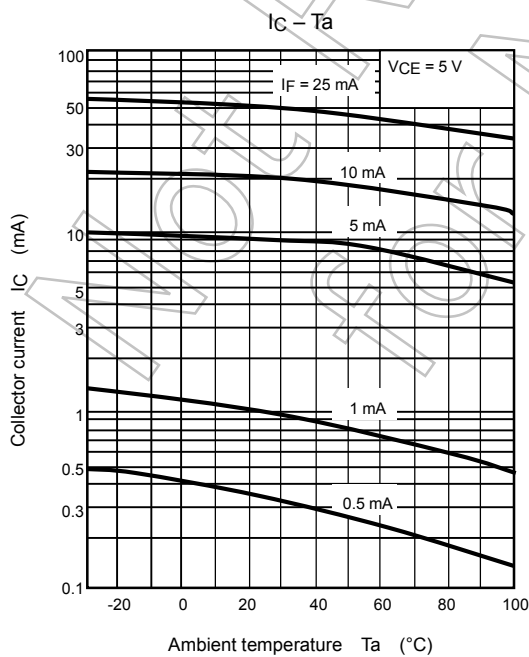
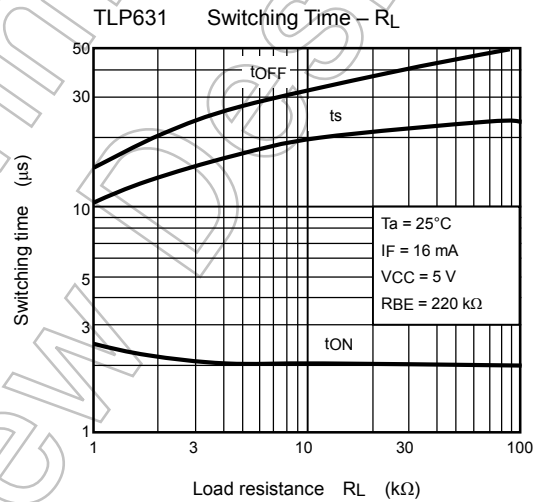
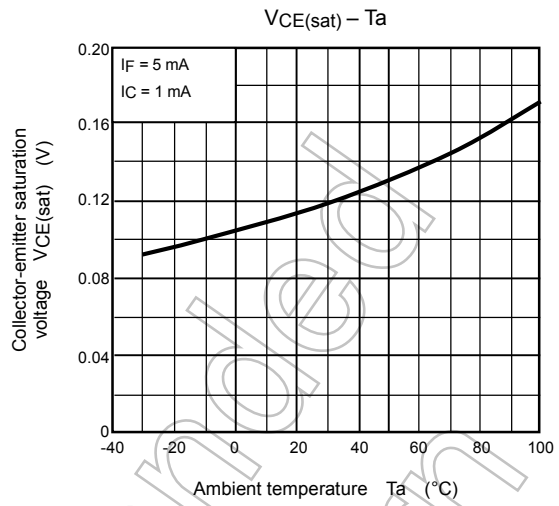
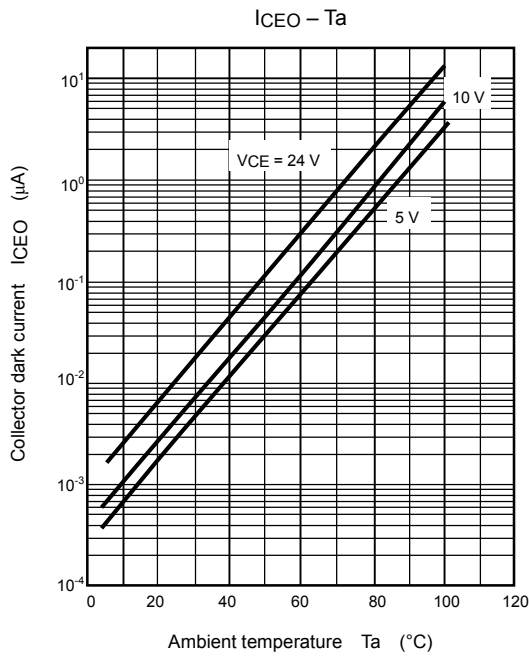
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	tr	VCC = 10 V, Ic = 2 mA RL = 100Ω	—	2	—	μs
Fall time	tf		—	3	—	
Turn-on time	ton		—	3	—	
Turn-off time	toff		—	3	—	
Turn-on time	tON	RL = 1.9 kΩ (Fig.1) RBE = OPEN VCC = 5 V, IF = 16 mA	—	2	—	μs
Storage time	ts		—	15	—	
Turn-off time	toFF		—	25	—	
Turn-on time	tON	RL = 1.9 kΩ (Fig.1) RBE = 220 kΩ (TLP631) VCC = 5 V, IF = 16 mA	—	2	—	μs
Storage time	ts		—	12	—	
Turn-off time	toFF		—	20	—	

Fig. 1 Switching time test circuit









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